

## ELECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

**Title of  
Invention**

METHOD OF FORMING STRAINED SILICON MATERIALS  
WITH IMPROVED THERMAL CONDUCTIVITY

Application Number : 10/710,826

Confirmation Number: 8/5/04

First Named Applicant: Stephen Bedell

Attorney Docket Number: FIS920040069

Art Unit: 2813

Examiner: Heather Doty

Search string: (20040004271).pn

### US Published Applications

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
FD	1	20040004271	2004-01-08	Fukuda et al.			

### Signature

Examiner Name	Date
Heather Doty	10/21/05